

V-Band Low Noise Amplifier, 50 to 75 GHz, 40 dB Gain, 3.0 dB NF

Description:

Model SBL-5037534025-1515-E1 is a low noise amplifier with a typical small signal gain of 40 dB and a nominal noise figure of 3.0 dB across the frequency range of 50 to 75 GHz. The DC power requirement for the amplifier is $+8~V_{DC}/250~mA$. The mechanical configuration offers an in line structure with WR-15 waveguides and UG-385/U anti-cocking flanges. Other port configurations, such as with 1 mm connectors or a



right angle structure with WR-15 waveguides, are also available under different model numbers.

Features:

- Full Waveguide Band Performance
- State-of-the-Art Noise Figure
- High Gain

Applications:

- IEEE 802.11ab WiGig
- Low Noise Receivers
- Communication Systems
- Test Equipment

Electrical Specifications:

Parameter	Minimum	Typical	Maximum
Frequency	50 GHz		75 GHz
Gain		40 dB	
Noise Figure		3.0 dB	
P_{1dB}		+12 dBm	
P _{in}			+5 dBm
Input Return Loss		10 dB	
Output Return Loss		10 dB	
DC Voltage	+6 V _{DC}	+8 V _{DC}	+15 V _{DC}
DC Supply Current	- //A	250 mA	
Specification Temperature		+25 °C	
Operating Temperature	0 °C		+50 °C

Mechanical Specifications:

Item	Specification	
Input	WR-15 Waveguide with UG-385/U Anti-Cocking Flange	
Output	WR-15 Waveguide with UG-385/U Anti-Cocking Flange	
Bias	Solder Pin	
Case Material	Aluminum	
Finish	Gold Plated	
Weight	1.6 Oz	
Size	1.10" (W) 1.50" (L) X 0.75" (H)	
Outline	BG-SV-2-A	



www.eravant.com | 501 Amapola Avenue, Torrance, CA 90501 Phone: 424-757-0168 | Fax: 424-757-0188 | Email: support@eravant.com



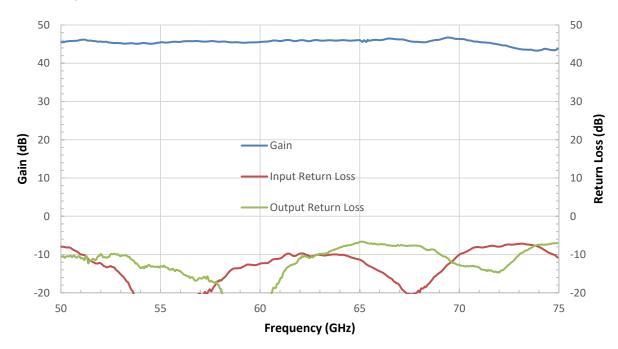
Copyright © 2022 by Eravant

9

V-Band Low Noise Amplifier, 50 to 75 GHz, 40 dB Gain, 3.0 dB NF

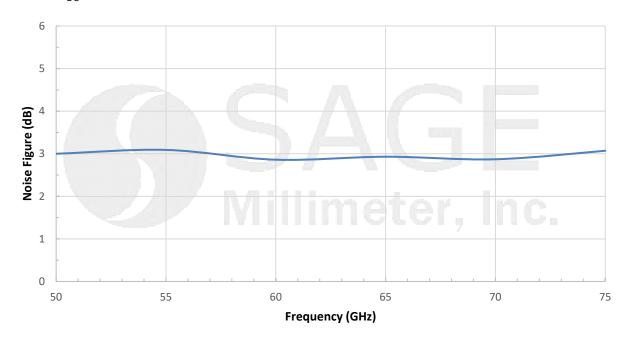
Typical Gain and Return Loss vs. Frequency

Bias: $+8 V_{DC}/250 \text{ mA}$



Typical Noise Figure vs. Frequency

Bias: $+8V_{DC}/250 \text{ mA}$





(ESD

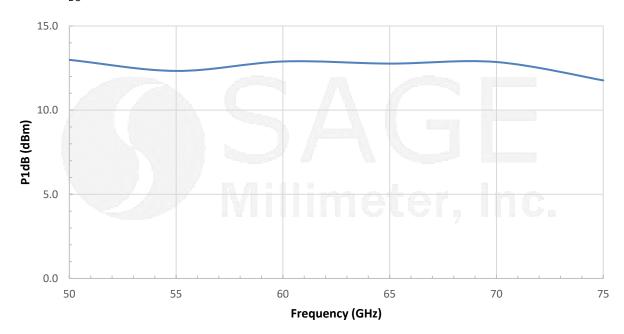
www.eravant.com | 501 Amapola Avenue, Torrance, CA 90501 Phone: 424-757-0168 | Fax: 424-757-0188 | Email: support@eravant.com



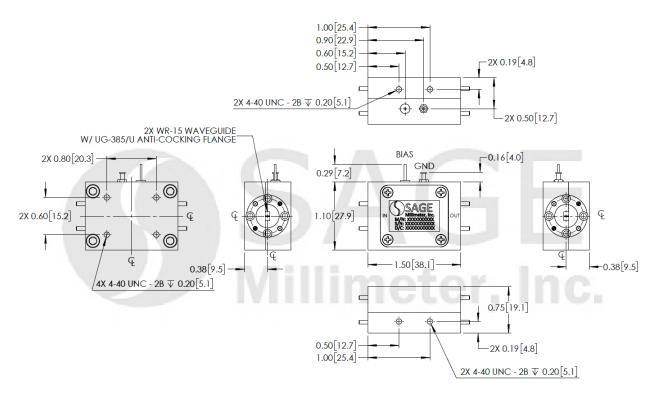
V-Band Low Noise Amplifier, 50 to 75 GHz, 40 dB Gain, 3.0 dB NF

Typical P1dB vs. Frequency

Bias: +8 V_{DC}/250 mA



Mechanical Outline: (Unless otherwise specified, all dimensions are in inches [millimeters])





ESD

www.eravant.com | 501 Amapola Avenue, Torrance, CA 90501 Phone: 424-757-0168 | Fax: 424-757-0188 | Email: support@eravant.com



V-Band Low Noise Amplifier, 50 to 75 GHz, 40 dB Gain, 3.0 dB NF

Note:

- All data presented is collected from a sample lot. Actual data may vary unit to unit.
- All testing was performed under +25 °C case temperature.
- Eravant reserves the right to change the information presented without notice.
- Other mechanical configurations are available under different model numbers.

Caution:

- Exceeding absolute maximum ratings shown will damage the device.
- The device is static sensitive. Always follow ESD rules when working with the device.
- The case temperature of the device shall never exceed +50 °C. Use proper heatsink or fan if necessary.
- Any foreign objects in the waveguide will cause performance degradation and may damage the device.





ESD

www.eravant.com | 501 Amapola Avenue, Torrance, CA 90501 Phone: 424-757-0168 | Fax: 424-757-0188 | Email: support@eravant.com